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Applications of "[Embedded - Microcontrollers](#)"

Details

Product Status	Not For New Designs
Core Processor	Coldfire V2
Core Size	32-Bit Single-Core
Speed	66MHz
Connectivity	CANbus, I ² C, SPI, UART/USART
Peripherals	DMA, LVD, POR, PWM, WDT
Number of I/O	55
Program Memory Size	256KB (256K x 8)
Program Memory Type	FLASH
EEPROM Size	-
RAM Size	32K x 8
Voltage - Supply (Vcc/Vdd)	3V ~ 3.6V
Data Converters	A/D 8x12b
Oscillator Type	Internal
Operating Temperature	-40°C ~ 85°C (TA)
Mounting Type	Surface Mount
Package / Case	100-LQFP
Supplier Device Package	100-LQFP (14x14)
Purchase URL	https://www.e-xfl.com/product-detail/nxp-semiconductors/mcf5213caf66

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- Error-detection capabilities
- Modem support includes request-to-send (RTS) and clear-to-send (CTS) lines for two UARTs
- Transmit and receive FIFO buffers
- I²C module
 - Interchip bus interface for EEPROMs, LCD controllers, A/D converters, and keypads
 - Fully compatible with industry-standard I²C bus
 - Master and slave modes support multiple masters
 - Automatic interrupt generation with programmable level
- Queued serial peripheral interface (QSPI)
 - Full-duplex, three-wire synchronous transfers
 - Up to four chip selects available
 - Master mode operation only
 - Programmable bit rates up to half the CPU clock frequency
 - Up to 16 pre-programmed transfers
- Fast analog-to-digital converter (ADC)
 - Eight analog input channels
 - 12-bit resolution
 - Minimum 1.125 μ s conversion time
 - Simultaneous sampling of two channels for motor control applications
 - Single-scan or continuous operation
 - Optional interrupts on conversion complete, zero crossing (sign change), or under/over low/high limit
 - Unused analog channels can be used as digital I/O
- Four 32-bit timers with DMA support
 - 12.5 ns resolution at 80 MHz
 - Programmable sources for clock input, including an external clock option
 - Programmable prescaler
 - Input capture capability with programmable trigger edge on input pin
 - Output compare with programmable mode for the output pin
 - Free run and restart modes
 - Maskable interrupts on input capture or output compare
 - DMA trigger capability on input capture or output compare
- Four-channel general purpose timer
 - 16-bit architecture
 - Programmable prescaler
 - Output pulse-widths variable from microseconds to seconds
 - Single 16-bit input pulse accumulator
 - Toggle-on-overflow feature for pulse-width modulator (PWM) generation
 - One dual-mode pulse accumulation channel
- Pulse-width modulation timer
 - Operates as eight channels with 8-bit resolution or four channels with 16-bit resolution
 - Programmable period and duty cycle
 - Programmable enable/disable for each channel
 - Software selectable polarity for each channel
 - Period and duty cycle are double buffered. Change takes effect when the end of the current period is reached (PWM counter reaches zero) or when the channel is disabled.

- Programmable center or left aligned outputs on individual channels
- Four clock sources (A, B, SA, and SB) provide for a wide range of frequencies
- Emergency shutdown
- Two periodic interrupt timers (PITs)
 - 16-bit counter
 - Selectable as free running or count down
- Software watchdog timer
 - 32-bit counter
 - Low-power mode support
- Clock generation features
 - One to 48 MHz crystal, 8 MHz on-chip relaxation oscillator, or external oscillator reference options
 - Trimmed relaxation oscillator
 - Two to 10 MHz reference frequency for normal PLL mode with a pre-divider programmable from 1 to 8
 - System can be clocked from PLL or directly from crystal oscillator or relaxation oscillator
 - Low power modes supported
 - 2^n ($n \leq 0 \leq 15$) low-power divider for extremely low frequency operation
- Interrupt controller
 - Uniquely programmable vectors for all interrupt sources
 - Fully programmable level and priority for all peripheral interrupt sources
 - Seven external interrupt signals with fixed level and priority
 - Unique vector number for each interrupt source
 - Ability to mask any individual interrupt source or all interrupt sources (global mask-all)
 - Support for hardware and software interrupt acknowledge (IACK) cycles
 - Combinatorial path to provide wake-up from low-power modes
- DMA controller
 - Four fully programmable channels
 - Dual-address transfer support with 8-, 16-, and 32-bit data capability, along with support for 16-byte (4×32-bit) burst transfers
 - Source/destination address pointers that can increment or remain constant
 - 24-bit byte transfer counter per channel
 - Auto-alignment transfers supported for efficient block movement
 - Bursting and cycle steal support
 - Software-programmable DMA requesters for the UARTs (3) and 32-bit timers (4)
- Reset
 - Separate reset in and reset out signals
 - Seven sources of reset:
 - Power-on reset (POR)
 - External
 - Software
 - Watchdog
 - Loss of clock
 - Loss of lock
 - Low-voltage detection (LVD)
 - Status flag indication of source of last reset
- Chip integration module (CIM)

Figure 2 shows the pinout configuration for the 100 LQFP.

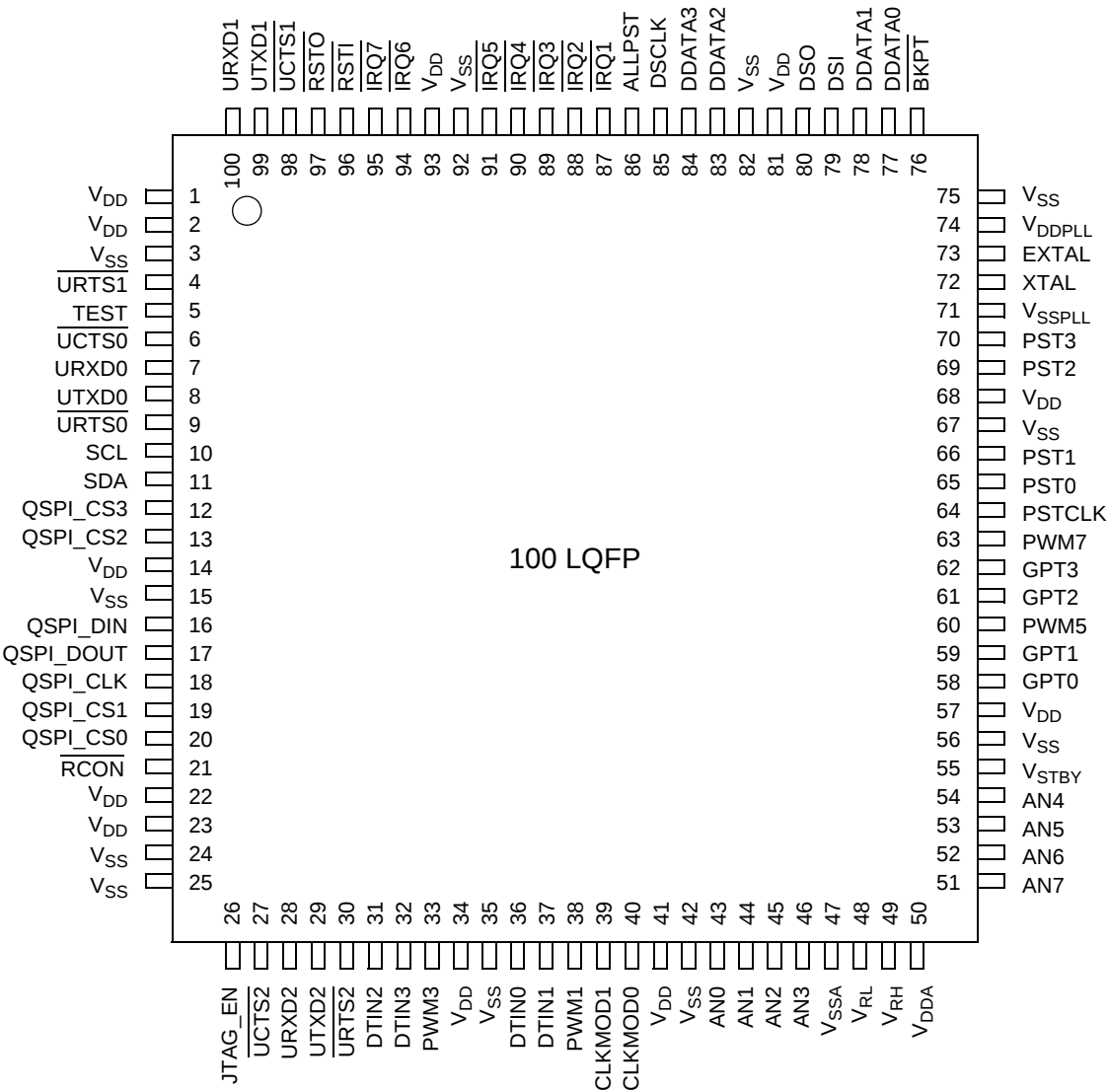


Figure 2. 100 LQFP Pin Assignments

MCF5213 Family Configurations

Figure 3 shows the pinout configuration for the 81 MAPBGA.

	1	2	3	4	5	6	7	8	9
A	V _{SS}	UTXD1	$\overline{\text{RSTI}}$	$\overline{\text{IRQ5}}$	$\overline{\text{IRQ3}}$	ALLPST	TDO	TMS	V _{SS}
B	$\overline{\text{URTS1}}$	URXD1	$\overline{\text{RSTO}}$	$\overline{\text{IRQ6}}$	$\overline{\text{IRQ2}}$	$\overline{\text{TRST}}$	TDI	V _{DD} PLL	EXTAL
C	$\overline{\text{UCTS0}}$	TEST	$\overline{\text{UCTS1}}$	$\overline{\text{IRQ7}}$	$\overline{\text{IRQ4}}$	$\overline{\text{IRQ1}}$	TCLK	V _{SS} PLL	XTAL
D	URXD0	UTXD0	$\overline{\text{URTS0}}$	V _{SS}	V _{DD}	V _{SS}	PWM7	GPT3	GPT2
E	SCL	SDA	V _{DD}	V _{DD}	V _{DD}	V _{DD}	V _{DD}	PWM5	GPT1
F	QSPI_CS3	QSPI_CS2	QSPI_DIN	V _{SS}	V _{DD}	V _{SS}	GPT0	V _{STBY}	AN4
G	QSPI_DOUT	QSPI_CLK	$\overline{\text{RCON}}$	DTIN1	CLKMOD0	AN2	AN3	AN5	AN6
H	QSPI_CS0	QSPI_CS1	DTIN3	DTIN0	CLKMOD1	AN1	V _{SSA}	V _{DDA}	AN7
J	V _{SS}	JTAG_EN	DTIN2	PWM3	PWM1	AN0	V _{RL}	V _{RH}	V _{SSA}

Figure 3. 81 MAPBGA Pin Assignments

Figure 4 shows the pinout configuration for the 64 LQFP and 64 QFN.

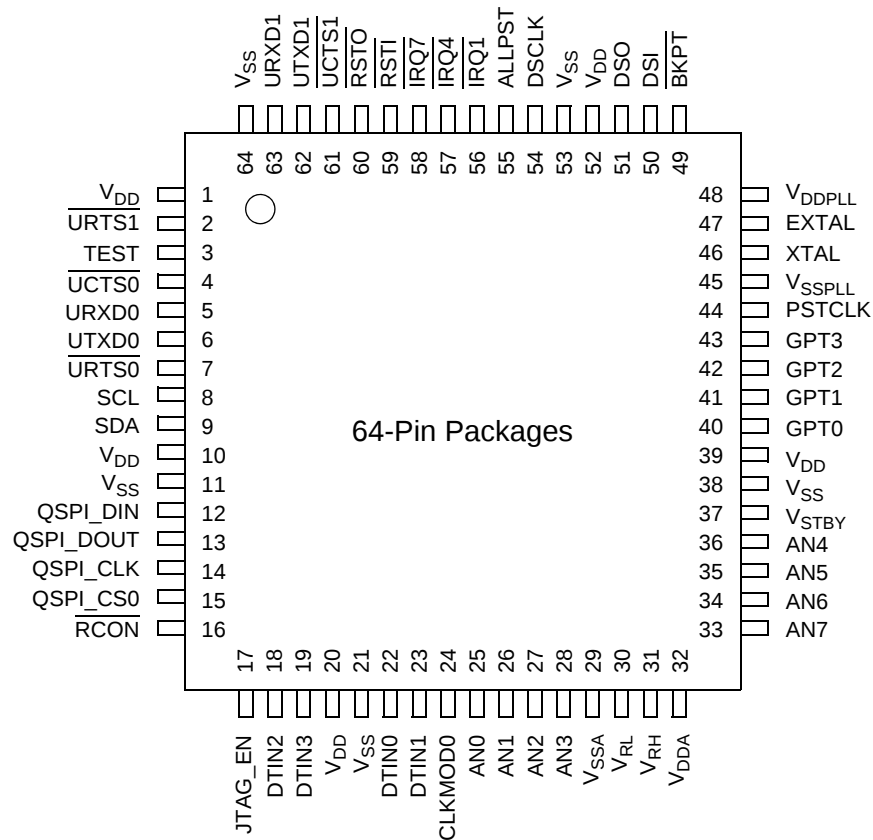


Figure 4. 64 LQFP and 64 QFN Pin Assignments

Table 3 shows the pin functions by primary and alternate purpose, and illustrates which packages contain each pin.

1.2 Reset Signals

Table 4 describes signals used to reset the chip or as a reset indication.

Table 4. Reset Signals

Signal Name	Abbreviation	Function	I/O
Reset In	$\overline{\text{RSTI}}$	Primary reset input to the device. Asserting $\overline{\text{RSTI}}$ for at least 8 CPU clock cycles immediately resets the CPU and peripherals.	I
Reset Out	$\overline{\text{RSTO}}$	Driven low for 1024 CPU clocks after the reset source has deasserted.	O

1.3 PLL and Clock Signals

Table 5 describes signals used to support the on-chip clock generation circuitry.

Table 5. PLL and Clock Signals

Signal Name	Abbreviation	Function	I/O
External Clock In	EXTAL	Crystal oscillator or external clock input except when the on-chip relaxation oscillator is used.	I
Crystal	XTAL	Crystal oscillator output except when CLKMOD1=1, then sampled as part of the clock mode selection mechanism.	O
Clock Out	CLKOUT	This output signal reflects the internal system clock.	O

1.4 Mode Selection

Table 6 describes signals used in mode selection; Table 7 describes the particular clocking modes.

Table 6. Mode Selection Signals

Signal Name	Abbreviation	Function	I/O
Clock Mode Selection	CLKMOD[1:0]	Selects the clock boot mode.	I
Reset Configuration	RCON	The Serial Flash Programming mode is entered by asserting the RCON pin (with the TEST pin negated) as the chip comes out of reset. During this mode, the EzPort has access to the flash memory which can be programmed from an external device.	
Test	TEST	Reserved for factory testing only and in normal modes of operation should be connected to VSS to prevent unintentional activation of test functions.	I

Table 7. Clocking Modes

CLKMOD[1:0]	XTAL	Configure the clock mode.
00	0	PLL disabled, clock driven by external oscillator
00	1	PLL disabled, clock driven by on-chip oscillator
01	N/A	PLL disabled, clock driven by crystal
10	0	PLL in normal mode, clock driven by external oscillator
10	1	PLL in normal mode, clock driven by on-chip oscillator
11	N/A	PLL in normal mode, clock driven by crystal

1.8 UART Module Signals

Table 11 describes the UART module signals.

Table 11. UART Module Signals

Signal Name	Abbreviation	Function	I/O
Transmit Serial Data Output	UTXD n	Transmitter serial data outputs for the UART modules. The output is held high (mark condition) when the transmitter is disabled, idle, or in the local loopback mode. Data is shifted out, LSB first, on this pin at the falling edge of the serial clock source.	O
Receive Serial Data Input	URXD n	Receiver serial data inputs for the UART modules. Data is received on this pin LSB first. When the UART clock is stopped for power-down mode, any transition on this pin restarts the clock.	I
Clear-to-Send	$\overline{\text{UCTS}}_n$	Indication to the UART modules that they can begin data transmission.	I
Request-to-Send	$\overline{\text{URTS}}_n$	Automatic request-to-send outputs from the UART modules. This signal can also be configured to be asserted and negated as a function of the RxFIFO level.	O

1.9 DMA Timer Signals

Table 12 describes the signals of the four DMA timer modules.

Table 12. DMA Timer Signals

Signal Name	Abbreviation	Function	I/O
DMA Timer Input	DTIN	Event input to the DMA timer modules.	I
DMA Timer Output	DTOUT	Programmable output from the DMA timer modules.	O

1.10 ADC Signals

Table 13 describes the signals of the Analog-to-Digital Converter.

Table 13. ADC Signals

Signal Name	Abbreviation	Function	I/O
Analog Inputs	AN[7:0]	Inputs to the analog-to-digital converter.	I
Analog Reference	V _{RH}	Reference voltage high and low inputs.	I
	V _{RL}		I
Analog Supply	V _{DDA}	Isolate the ADC circuitry from power supply noise.	—
	V _{SSA}		—
ADC Sync Inputs	SYNCA / SYNCB	These signals can initiate an analog-to-digital conversion process.	I

Table 16. Debug Support Signals (continued)

Signal Name	Abbreviation	Function	I/O
Development Serial Input	DSI	Development Serial Input - Internally synchronized input that provides data input for the serial communication port to the debug module, after the DSCLK has been seen as high (logic 1).	I
Development Serial Output	DSO	Development Serial Output - Provides serial output communication for debug module responses. DSO is registered internally. The output is delayed from the validation of DSCLK high.	O
Debug Data	DDATA[3:0]	Display captured processor data and breakpoint status. The CLKOUT signal can be used by the development system to know when to sample DDATA[3:0].	O
Processor Status Clock	PSTCLK	Processor Status Clock - Delayed version of the processor clock. Its rising edge appears in the center of valid PST and DDATA output. PSTCLK indicates when the development system should sample PST and DDATA values. If real-time trace is not used, setting CSR[PCD] keeps PSTCLK, and PST and DDATA outputs from toggling without disabling triggers. Non-quiescent operation can be reenabled by clearing CSR[PCD], although the external development systems must resynchronize with the PST and DDATA outputs. PSTCLK starts clocking only when the first non-zero PST value (0xC, 0xD, or 0xF) occurs during system reset exception processing.	O
Processor Status Outputs	PST[3:0]	Indicate core status. Debug mode timing is synchronous with the processor clock; status is unrelated to the current bus transfer. The CLKOUT signal can be used by the development system to know when to sample PST[3:0].	O
All Processor Status Outputs	ALLPST	Logical AND of PST[3:0]. The CLKOUT signal can be used by the development system to know when to sample ALLPST.	O

1.14 EzPort Signal Descriptions

Table contains a list of EzPort external signals.

Table 17. EzPort Signal Descriptions

Signal Name	Abbreviation	Function	I/O
EzPort Clock	EZPCK	Shift clock for EzPort transfers.	I
EzPort Chip Select	EZPCS	Chip select for signalling the start and end of serial transfers.	I
EzPort Serial Data In	EZPD	EZPD is sampled on the rising edge of EZPCK.	I
EzPort Serial Data Out	EZPQ	EZPQ transitions on the falling edge of EZPCK.	O

Table 22. Thermal Characteristics (continued)

	Characteristic		Symbol	Value	Unit
81 MAPBGA	Junction to ambient, natural convection	Single layer board (1s)	θ_{JA}	61 ^{1,2}	°C/W
	Junction to ambient, natural convection	Four layer board (2s2p)	θ_{JA}	35 ^{2,3}	°C/W
	Junction to ambient, (@200 ft/min)	Single layer board (1s)	θ_{JMA}	50 ^{2,3}	°C/W
	Junction to ambient, (@200 ft/min)	Four layer board (2s2p)	θ_{JMA}	31 ^{2,3}	°C/W
	Junction to board	—	θ_{JB}	20 ⁴	°C/W
	Junction to case	—	θ_{JC}	12 ⁵	°C/W
	Junction to top of package	Natural convection	Ψ_{jt}	2 ⁶	°C/W
	Maximum operating junction temperature	—	T_j	105	°C
64 LQFP	Junction to ambient, natural convection	Single layer board (1s)	θ_{JA}	62 ^{1,2}	°C/W
	Junction to ambient, natural convection	Four layer board (2s2p)	θ_{JA}	43 ^{1,3}	°C/W
	Junction to ambient (@200 ft/min)	Single layer board (1s)	θ_{JMA}	50 ^{1,3}	°C/W
	Junction to ambient (@200 ft/min)	Four layer board (2s2p)	θ_{JMA}	36 ^{1,3}	°C/W
	Junction to board	—	θ_{JB}	26 ⁴	°C/W
	Junction to case	—	θ_{JC}	9 ⁵	°C/W
	Junction to top of package	Natural convection	Ψ_{jt}	2 ⁶	°C/W
	Maximum operating junction temperature	—	T_j	105	°C
64 QFN	Junction to ambient, natural convection	Single layer board (1s)	θ_{JA}	68 ^{1,2}	°C/W
	Junction to ambient, natural convection	Four layer board (2s2p)	θ_{JA}	24 ^{1,3}	°C/W
	Junction to ambient (@200 ft/min)	Single layer board (1s)	θ_{JMA}	55 ^{1,3}	°C/W
	Junction to ambient (@200 ft/min)	Four layer board (2s2p)	θ_{JMA}	19 ^{1,3}	°C/W
	Junction to board	—	θ_{JB}	8 ⁴	°C/W
	Junction to case (bottom)	—	θ_{JC}	0.6 ⁵	°C/W
	Junction to top of package	Natural convection	Ψ_{jt}	3 ⁶	°C/W
	Maximum operating junction temperature	—	T_j	105	°C

¹ θ_{JA} and Ψ_{jt} parameters are simulated in conformance with EIA/JESD Standard 51-2 for natural convection. Freescale recommends the use of θ_{JA} and power dissipation specifications in the system design to prevent device junction temperatures from exceeding the rated specification. System designers should be aware that device junction temperatures can be significantly influenced by board layout and surrounding devices. Conformance to the device junction temperature specification can be verified by physical measurement in the customer's system using the Ψ_{jt} parameter, the device power dissipation, and the method described in EIA/JESD Standard 51-2.

² Per JEDEC JESD51-2 with the single-layer board (JESD51-3) horizontal.

³ Per JEDEC JESD51-6 with the board JESD51-7) horizontal.

⁴ Thermal resistance between the die and the printed circuit board in conformance with JEDEC JESD51-8. Board temperature is measured on the top surface of the board near the package.

⁵ Thermal resistance between the die and the case top surface as measured by the cold plate method (MIL SPEC-883 Method 1012.1).

⁶ Thermal characterization parameter indicating the temperature difference between package top and the junction temperature per JEDEC JESD51-2. When Greek letters are not available, the thermal characterization parameter is written in conformance with Psi-JT.

2.5 ESD Protection

Table 25. ESD Protection Characteristics^{1, 2}

Characteristics	Symbol	Value	Units
ESD target for Human Body Model	HBM	2000	V
ESD target for Machine Model	MM	200	V
HBM circuit description	R _{series}	1500	Ω
	C	100	pF
MM circuit description	R _{series}	0	Ω
	C	200	pF
Number of pulses per pin (HBM)			
• Positive pulses	—	1	—
• Negative pulses	—	1	—
Number of pulses per pin (MM)			
• Positive pulses	—	3	—
• Negative pulses	—	3	—
Interval of pulses	—	1	sec

¹ All ESD testing is in conformity with CDF-AEC-Q100 Stress Test Qualification for Automotive Grade Integrated Circuits.

² A device is defined as a failure if after exposure to ESD pulses the device no longer meets the device specification requirements. Complete DC parametric and functional testing is performed per applicable device specification at room temperature followed by hot temperature, unless specified otherwise in the device specification.

2.6 DC Electrical Specifications

Table 26. DC Electrical Specifications¹

Characteristic	Symbol	Min	Max	Unit
Supply voltage	V _{DD}	3.0	3.6	V
Standby voltage	V _{STBY}	3.0	3.6	V
Input high voltage	V _{IH}	0.7 × V _{DD}	4.0	V
Input low voltage	V _{IL}	V _{SS} – 0.3	0.35 × V _{DD}	V
Input hysteresis	V _{HYS}	0.06 × V _{DD}	—	mV
Low-voltage detect trip voltage (V _{DD} falling)	V _{LVD}	2.15	2.3	V
Low-voltage detect hysteresis (V _{DD} rising)	V _{LVDHYS}	60	120	mV
Input leakage current V _{in} = V _{DD} or V _{SS} , digital pins	I _{in}	–1.0	1.0	μA
Output high voltage (all input/output and all output pins) I _{OH} = –2.0 mA	V _{OH}	V _{DD} – 0.5	—	V
Output low voltage (all input/output and all output pins) I _{OL} = 2.0mA	V _{OL}	—	0.5	V

Table 26. DC Electrical Specifications (continued)¹

Characteristic	Symbol	Min	Max	Unit
Output high voltage (high drive) $I_{OH} = -5 \text{ mA}$	V_{OH}	$V_{DD} - 0.5$	—	V
Output low voltage (high drive) $I_{OL} = 5 \text{ mA}$	V_{OL}	—	0.5	V
Output high voltage (low drive) $I_{OH} = -2 \text{ mA}$	V_{OH}	$V_{DD} - 0.5$	—	V
Output low voltage (low drive) $I_{OL} = 2 \text{ mA}$	V_{OL}	—	0.5	V
Weak internal pull Up device current, tested at $V_{IL} \text{ Max.}^2$	I_{APU}	-10	-130	μA
Input Capacitance ³ • All input-only pins • All input/output (three-state) pins	C_{in}	— —	7 7	pF

¹ Refer to Table 27 for additional PLL specifications.

² Refer to Table 3 for pins having internal pull-up devices.

³ This parameter is characterized before qualification rather than 100% tested.

2.7 Clock Source Electrical Specifications

Table 27. PLL Electrical Specifications

(V_{DD} and $V_{DDPLL} = 2.7$ to 3.6 V , $V_{SS} = V_{SSPLL} = 0 \text{ V}$)

Characteristic	Symbol	Min	Max	Unit
PLL reference frequency range • Crystal reference • External reference	$f_{ref_crystal}$ f_{ref_ext}	2 2	10.0 10.0	MHz
System frequency ¹ • External clock mode • On-chip PLL frequency	f_{sys}	0 $f_{ref} / 32$	66.67 or 80 ² 66.67 or 80 ²	MHz
Loss of reference frequency ^{3, 5}	f_{LOR}	100	1000	kHz
Self clocked mode frequency ⁴	f_{SCM}	1	5	MHz
Crystal start-up time ^{5, 6}	t_{cst}	—	10	ms
EXTAL input high voltage • External reference	V_{IHEXT}	2.0	V_{DD}	V
EXTAL input low voltage • External reference	V_{ILEXT}	V_{SS}	0.8	V
PLL lock time ^{4, 7}	t_{pll}	—	500	μs
Duty cycle of reference ⁴	t_{dc}	40	60	% f_{ref}

Table 27. PLL Electrical Specifications (continued)
 $(V_{DD} \text{ and } V_{DDPLL} = 2.7 \text{ to } 3.6 \text{ V}, V_{SS} = V_{SSPLL} = 0 \text{ V})$

Characteristic	Symbol	Min	Max	Unit
Frequency un-LOCK range	f_{UL}	-1.5	1.5	% f_{ref}
Frequency LOCK range	f_{LCK}	-0.75	0.75	% f_{ref}
CLKOUT period jitter ^{4, 5, 8, 9} , measured at f_{SYS} Max • Peak-to-peak (clock edge to clock edge) • Long term (averaged over 2 ms interval)	C_{jitter}	— —	10 .01	% f_{sys}
On-chip oscillator frequency	f_{OCO}	7.84	8.16	MHz

¹ All internal registers retain data at 0 Hz.

² Depending on packaging; see [Table 2](#).

³ Loss of Reference Frequency is the reference frequency detected internally, which transitions the PLL into self clocked mode.

⁴ Self clocked mode frequency is the frequency at which the PLL operates when the reference frequency falls below f_{LOR} with default MFD/RFD settings.

⁵ This parameter is characterized before qualification rather than 100% tested.

⁶ Proper PC board layout procedures must be followed to achieve specifications.

⁷ This specification applies to the period required for the PLL to rellock after changing the MFD frequency control bits in the synthesizer control register (SYNCR).

⁸ Jitter is the average deviation from the programmed frequency measured over the specified interval at maximum f_{sys} . Measurements are made with the device powered by filtered supplies and clocked by a stable external clock signal. Noise injected into the PLL circuitry via V_{DDPLL} and V_{SSPLL} and variation in crystal oscillator frequency increase the C_{jitter} percentage for a given interval.

⁹ Based on slow system clock of 40 MHz measured at f_{sys} max.

2.8 General Purpose I/O Timing

GPIO can be configured for certain pins of the QSPI, DDR Control, timer, UART, and Interrupt interfaces. When in GPIO mode, the timing specification for these pins is given in [Table 28](#) and [Figure 5](#).

The GPIO timing is met under the following load test conditions:

- 50 pF / 50 Ω for high drive
- 25 pF / 25 Ω for low drive

Table 28. GPIO Timing

NUM	Characteristic	Symbol	Min	Max	Unit
G1	CLKOUT High to GPIO Output Valid	t_{CHPOV}	—	10	ns
G2	CLKOUT High to GPIO Output Invalid	t_{CHPOI}	1.5	—	ns
G3	GPIO Input Valid to CLKOUT High	t_{PVCH}	9	—	ns
G4	CLKOUT High to GPIO Input Invalid	t_{CHPI}	1.5	—	ns

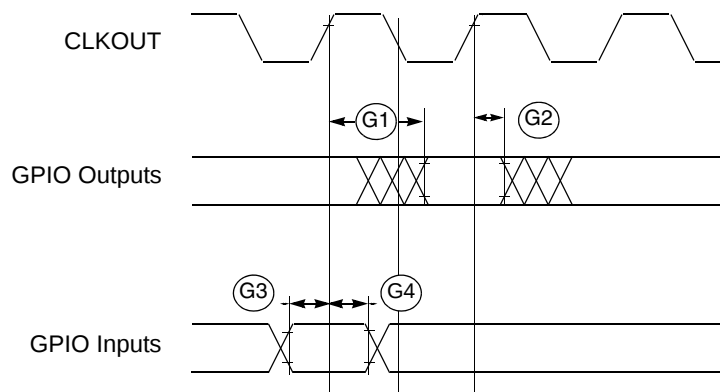


Figure 5. GPIO Timing

2.9 Reset Timing

Table 29. Reset and Configuration Override Timing

($V_{DD} = 2.7$ to 3.6 V, $V_{SS} = 0$ V, $T_A = T_L$ to T_H)¹

NUM	Characteristic	Symbol	Min	Max	Unit
R1	$\overline{RSTI}$ input valid to CLKOUT High	t_{RVCH}	9	—	ns
R2	CLKOUT High to $\overline{RSTI}$ Input invalid	t_{CHRI}	1.5	—	ns
R3	$\overline{RSTI}$ input valid time ²	t_{RIVT}	5	—	t_{CYC}
R4	CLKOUT High to $\overline{RSTO}$ Valid	t_{CHROV}	—	10	ns

¹ All AC timing is shown with respect to 50% V_{DD} levels unless otherwise noted.

² During low power STOP, the synchronizers for the $\overline{RSTI}$ input are bypassed and $\overline{RSTI}$ is asserted asynchronously to the system. Thus, $\overline{RSTI}$ must be held a minimum of 100 ns.

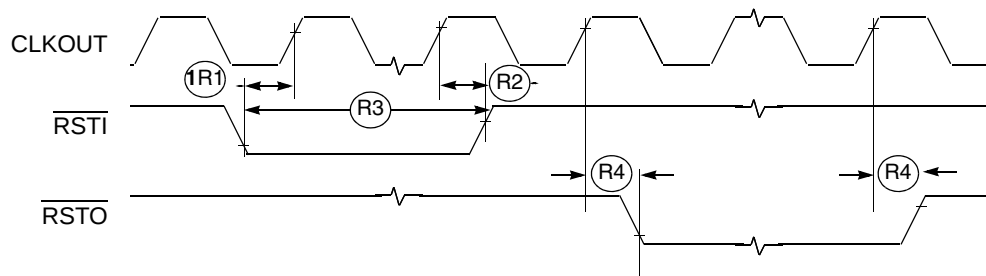


Figure 6. $\overline{RSTI}$ and Configuration Override Timing

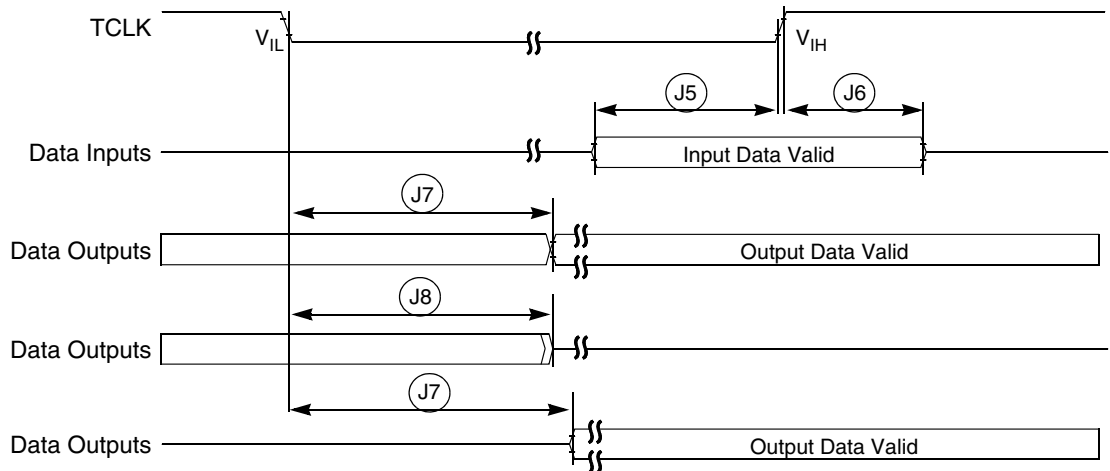


Figure 11. Boundary Scan (JTAG) Timing

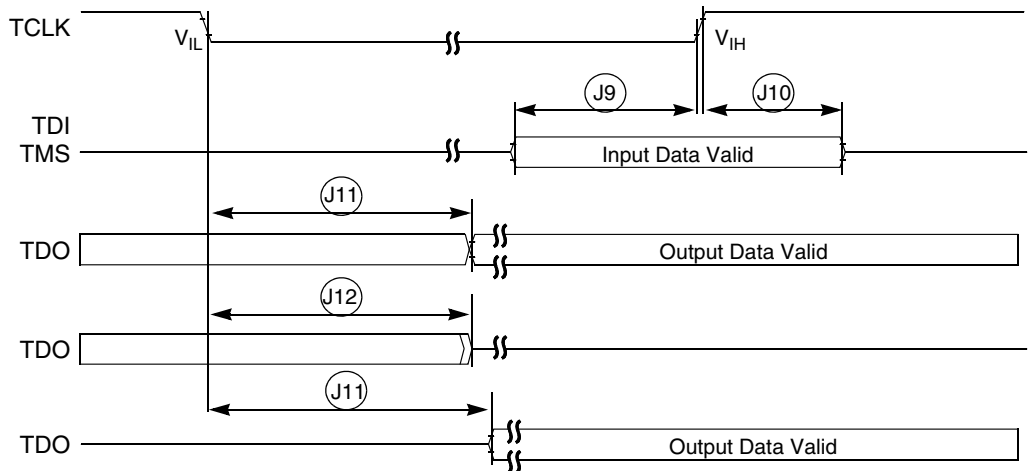


Figure 12. Test Access Port Timing

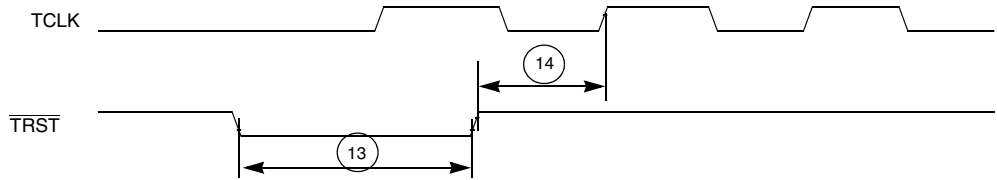


Figure 13. $\overline{TRST}$ Timing

Electrical Characteristics

Figure 15 shows BDM serial port AC timing for the values in Table 36.

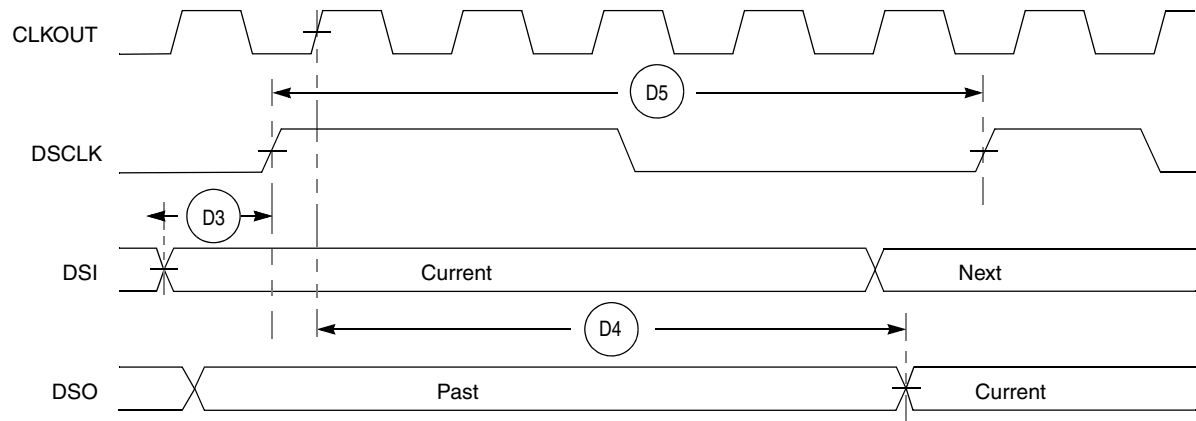
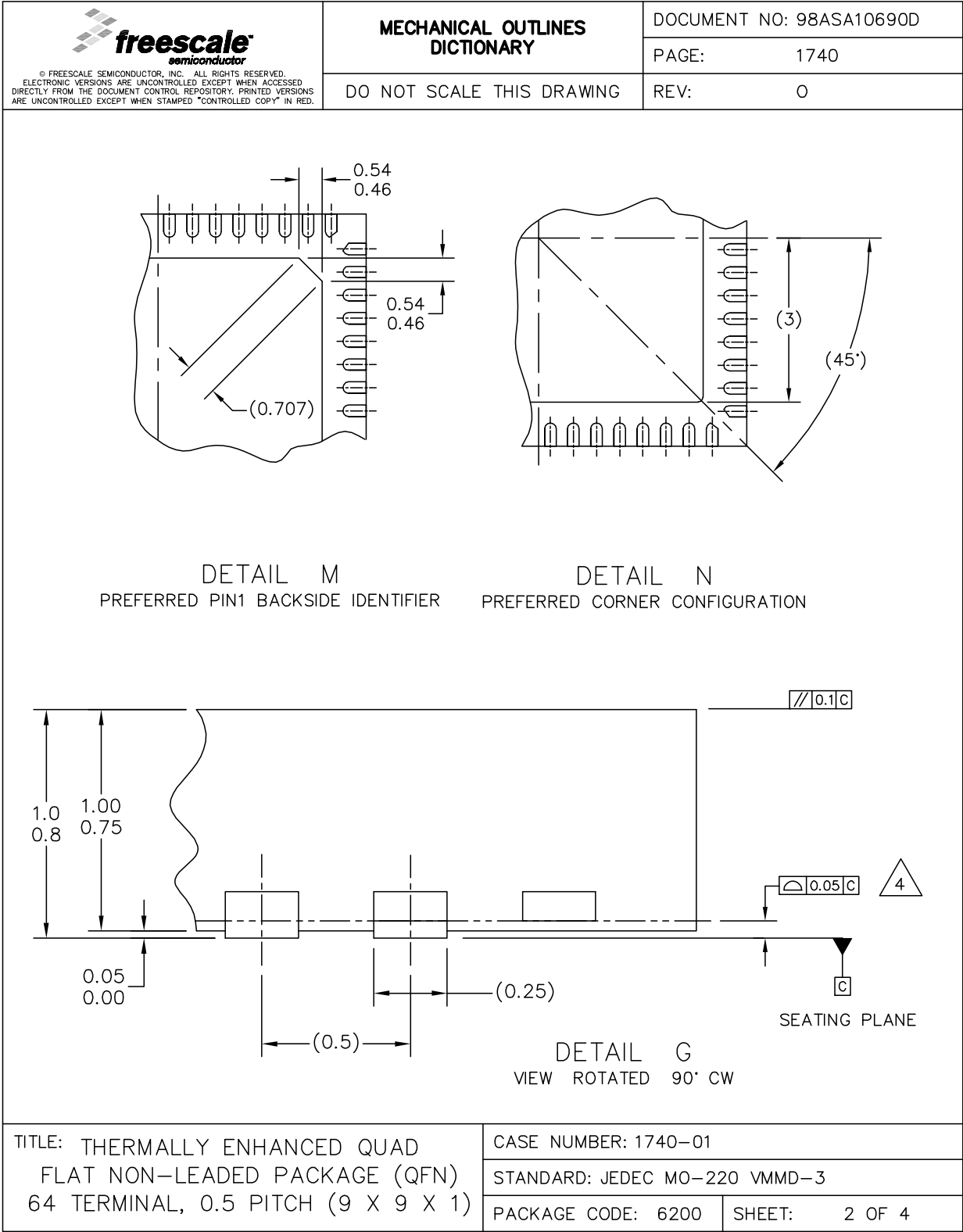
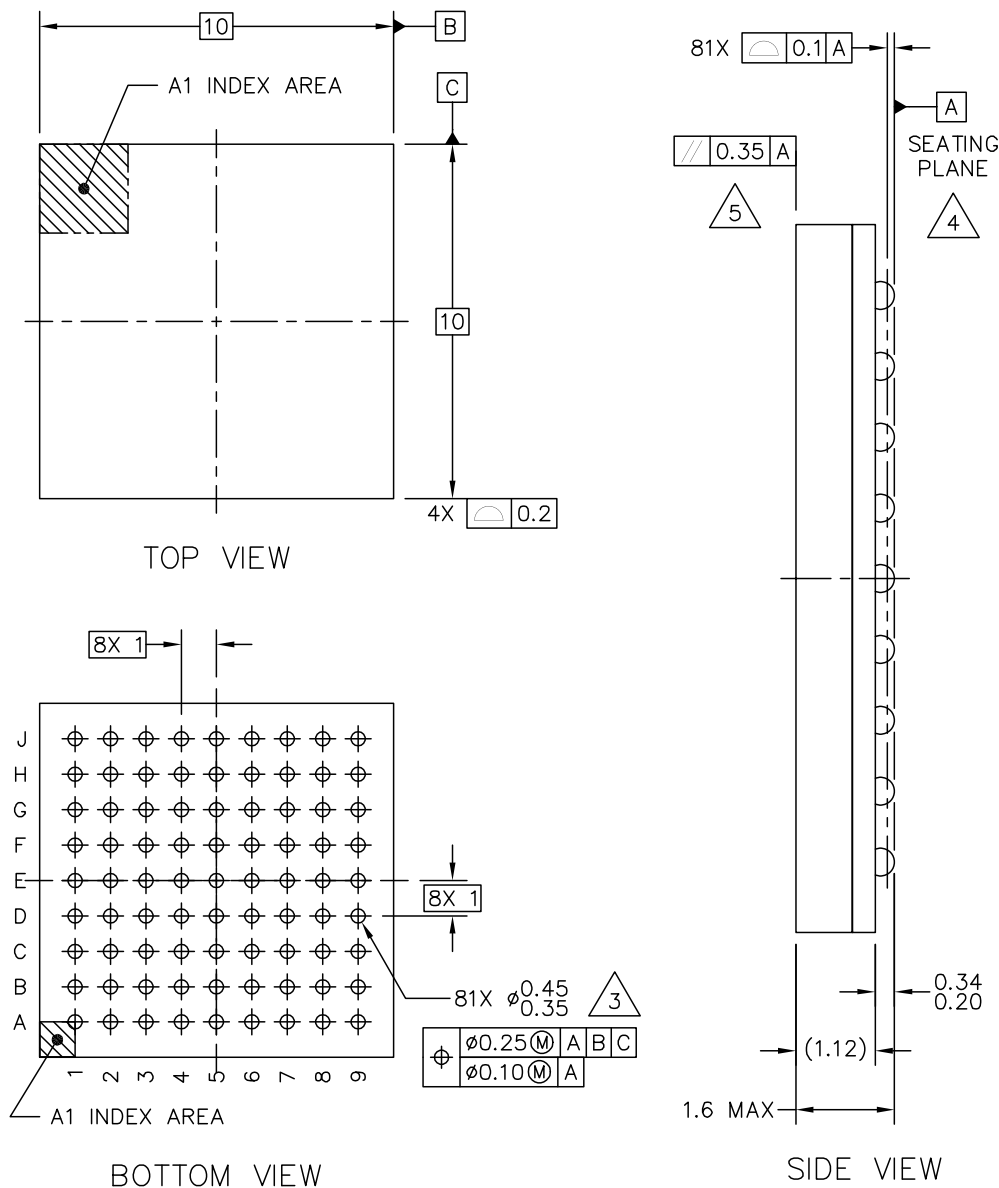


Figure 15. BDM Serial Port AC Timing



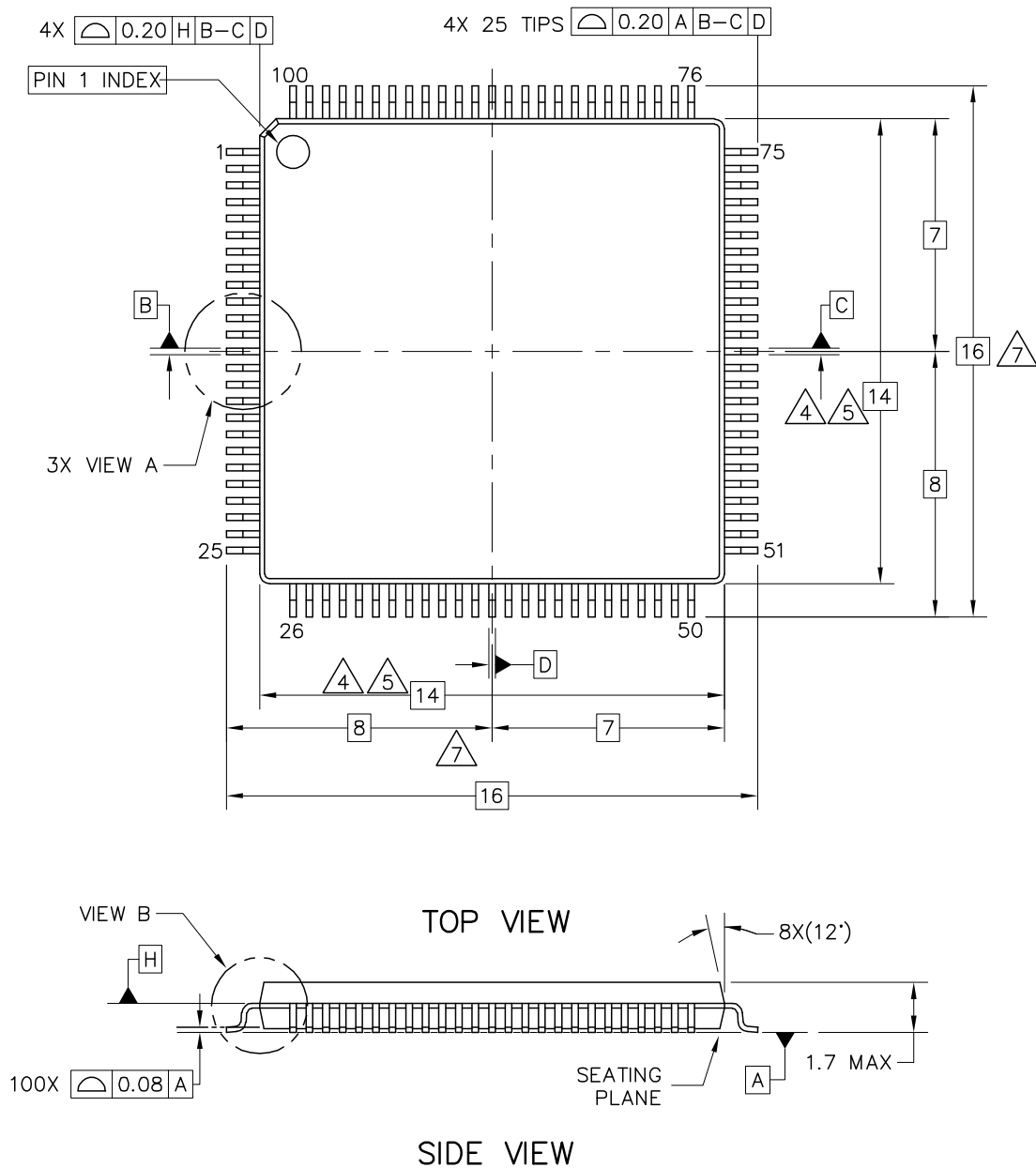
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0	ERIC TRIPLETT	RELEASED FOR PRODUCTION		TAYLOR LIU	27JUL2005
TITLE: THERMALLY ENHANCED QUAD FLAT NON-LEADED PACKAGE (QFN) 64 TERMINAL, 0.5 PITCH (9 X 9 X 1)			CASE NUMBER: 1740-01		
			STANDARD: JEDEC MO-220 VMMD-3		
			PACKAGE CODE: 6200	SHEET:	4 OF 4

3.3 81 MAPBGA Package



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	CASE NUMBER: 1662-01			04 FEB 2005	
	STANDARD: NON-JEDEC				

3.4 100-pin LQFP Package



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	CASE NUMBER: 983-03	07 APR 2005
	STANDARD: NON-JEDEC	